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Renesas Electronics Corporation

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RENESAS TECHNICAL UPDATE

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Product Category	MPU/MCU		Document No.	TN-H8*-A414A/E	Rev.	1.00
Title	The addition of H8/38606 Group		Information Category	Technical Notification		
Applicable Product	H8/38602R Group	Lot No.	Reference Document	H8/38602R Group Hardware Manual (REJ09B0152-0300 Rev.3.00)		
		All				

H8/38606 Group is added to H8/38602R Group.

The difference of the product specification of H8/38602R Group and H8/38606 Group is shown as follows. About the specifications except the following item, the product specification of H8/38606 Group and H8/38606 Group is equal.

Section 1 Overview

1.1 Features

- On-chip memory (H8/38602R Group Hardware Manual Rev.3.00 Page 1 of 516)

H8/38602R Group specification

Product Classification		Model	ROM	RAM
Flash memory version	H8/38602RF	HD64F38602R	16 Kbytes	1 Kbyte
Masked ROM version	H8/38602R	HD64338602R	16 Kbytes	1 Kbyte
	H8/38600R	HD64338600R	8 Kbytes	512 bytes

H8/38606 Group specification

Product Classification		Model	ROM	RAM
Flash memory version	H8/38606F	HD64F38606	48 Kbytes	2 Kbytes

- Compact package (H8/38602R Group Hardware Manual Rev.3.00 Page 2 of 516)

H8/38602R Group specification

Package	Code	Body Size	Pin Pitch	Remarks
P-VQFN-32	TNP-32	5x6mm	0.5mm	
P-LQFP-32	32P6U-A	7x7mm	0.8mm	

H8/38606 Group specification

Package	Code	Body Size	Pin Pitch	Remarks
P-VQFN-32	TNP-32	5x6mm	0.5mm	

Section 2 CPU

2.1 Address Space and Memory Map (H8/38602R Group Hardware Manual Rev.3.00 Page 8 of 516)

H8/38602R Group specification

HD64F38602R
(FLASH memory version)

H'0000 H'0050	Interrupt vector
H'3FFF	On-chip ROM (16Kbytes)
	Not used
H'F020 H'F100	Internal I/O registers
	Not used
H'FB80	On-chip RAM (1Kbyte)
H'FF80 H'FFFF	Internal I/O registers

HD64338602R
(Masked ROM version)

H'0000 H'0050	Interrupt vector
H'3FFF	On-chip ROM (16Kbytes)
	Not used
H'F020 H'F100	Internal I/O registers
	Not used
H'FB80	On-chip RAM (1Kbyte)
H'FF80 H'FFFF	Internal I/O registers

HD64338600R
(Masked ROM version)

H'0000 H'0050	Interrupt vector
H'1FFF	On-chip ROM (8Kbytes)
	Not used
H'F020 H'F100	Internal I/O registers
	Not used
H'FD80	On-chip RAM (512bytes)
H'FF80 H'FFFF	Internal I/O registers

H8/38606 Group specification

HD64F38606
(FLASH memory version)

H'0000 H'0050	Interrupt vector
H'BFFF	On-chip ROM (48Kbytes)
	Not used
H'F020 H'F100	Internal I/O registers
	Not used
H'F780	On-chip RAM (2Kbytes)
H'FF80 H'FFFF	Internal I/O registers

Section 6 ROM

- Programming/erasing methods (H8/38602R Group Hardware Manual Rev.3.00 Page 99 of 516)

H8/38602R Group specification

The flash memory is programmed 128 bytes at a time. Erasure is performed in single-block units. The flash memory is configured as follows: 1 Kbyte × 4 blocks and 12 Kbytes × 1 block. To erase the entire flash memory, each block must be erased in turn.

H8/38606 Group specification

The flash memory is programmed 128 bytes at a time. Erasure is performed in single-block units. The flash memory is configured as follows: 1 Kbyte × 4 blocks, 28 Kbytes × 1 block and 16 Kbytes × 1 block. To erase the entire flash memory, each block must be erased in turn.

6.1 Block Configuration (H8/38602R Group Hardware Manual Rev.3.00 Page 100 of 516)

H8/38602R Group specification

Figure 6.1(1) shows the block configuration of flash memory. The thick lines indicate erasing a block, the narrow lines indicate programming units, and the values are addresses. The 16-Kbyte flash memory is divided into 1 Kbyte × 4 blocks and 12 Kbytes × 1 block. Erasure is performed in these units. Programming is performed in 128-byte units starting from an address with lower eight bits H'00 or H'80.

Erasing unit 1 Kbyte	H'0000	H'0001	H'0002	Programming unit: 128 bytes	H'007F
	H'0080	H'0081	H'0082		H'00FF
Erasing unit 1 Kbyte	H'0380	H'0381	H'0382	Programming unit: 128 bytes	H'03FF
	H'0400	H'0401	H'0402		H'047F
Erasing unit 1 Kbyte	H'0480	H'0481	H'0482		H'04FF
	H'0780	H'0781	H'0782		H'07FF
Erasing unit 1 Kbyte	H'0800	H'0801	H'0802	Programming unit: 128 bytes	H'087F
	H'0880	H'0881	H'0882		H'08FF
Erasing unit 1 Kbyte	H'0B80	H'0B81	H'0B02		H'0BFF
	H'0C00	H'0C01	H'0C02	Programming unit: 128 bytes	H'0C7F
Erasing unit 1 Kbyte	H'0C80	H'0C81	H'0C82		H'0CFF
	H'0F80	H'0F81	H'0F82		H'0FFF
Erasing unit 12 Kbyte	H'1000	H'1001	H'1002	Programming unit: 128 bytes	H'107F
	H'1080	H'1081	H'1082		H'10FF
	H'3F80	H'3F81	H'3F82		H'3FFF

Figure 6.1(1) Flash Memory Block Configuration (H8/38602R Group)

H8/38606 Group specification

Figure 6.1(2) shows the block configuration of flash memory. The thick lines indicate erasing a block, the narrow lines indicate programming units, and the values are addresses. The 48-Kbyte flash memory is divided into 1 Kbyte × 4 blocks, 28 Kbytes × 1 block and 16 Kbytes × 1 block. Erasure is performed in these units. Programming is performed in 128-byte units starting from an address with lower eight bits H'00 or H'80.

Erasing unit 1 Kbyte	H'0000	H'0001	H'0002	Programming unit: 128 bytes	H'007F
	H'0080	H'0081	H'0082		H'00FF
Erasing unit 1 Kbyte	H'0380	H'0381	H'0382	Programming unit: 128 bytes	H'03FF
	H'0400	H'0401	H'0402		H'047F
Erasing unit 1 Kbyte	H'0480	H'0481	H'0482	Programming unit: 128 bytes	H'04FF
	H'0780	H'0781	H'0782		H'07FF
Erasing unit 1 Kbyte	H'0800	H'0801	H'0802	Programming unit: 128 bytes	H'087F
	H'0880	H'0881	H'0882		H'08FF
Erasing unit 1 Kbyte	H'0B80	H'0B81	H'0B02	Programming unit: 128 bytes	H'0BFF
	H'0C00	H'0C01	H'0C02		H'0C7F
Erasing unit 1 Kbyte	H'0C80	H'0C81	H'0C82	Programming unit: 128 bytes	H'0CFF
	H'0F80	H'0F81	H'0F82		H'0FFF
Erasing unit 28 Kbyte	H'1000	H'1001	H'1002	Programming unit: 128 bytes	H'107F
	H'1080	H'1081	H'1082		H'10FF
Erasing unit 16 Kbyte	H'7F80	H'7F81	H'7F82	Programming unit: 128 bytes	H'7FFF
	H'8000	H'8001	H'8002		H'807F
Erasing unit 16 Kbyte	H'8080	H'8081	H'8082	Programming unit: 128 bytes	H'80FF
	H'BF80	H'BF81	H'BF82		H'BFFF

Figure 6.1(2) Flash Memory Block Configuration (H8/38606 Group)

6.2 Register Description

6.2.3 Erase Block Register 1 (EBR1) (H8/38602R Group Hardware Manual Rev.3.00 Page 103 of 516)

H8/38602R Group specification

Bit	Bit Name	Initial Value	R/W	Description
7 to 5	-	All 0	-	Reserved Although these bits are readable/writable, only 0 should be written to.
4	EB4	0	R/W	When this bit is set to 1, a 12-Kbyte area of H'1000 to H'3FFF will be erased.
3	EB3	0	R/W	When this bit is set to 1, a 1-Kbyte area of H'0C00 to H'0FFF will be erased.
2	EB2	0	R/W	When this bit is set to 1, a 1-Kbyte area of H'0800 to H'0BFF will be erased.
1	EB1	0	R/W	When this bit is set to 1, a 1-Kbyte area of H'0400 to H'07FF will be erased.
0	EB0	0	R/W	When this bit is set to 1, a 1-Kbyte area of H'0000 to H'03FF will be erased.

H8/38606 Group specification

Bit	Bit Name	Initial Value	R/W	Description
7, 6	-	All 0	-	Reserved Although these bits are readable/writable, only 0 should be written to.
5	EB5	0	R/W	When this bit is set to 1, a 16-Kbyte area of H'8000 to H'BFFF will be erased.
4	EB4	0	R/W	When this bit is set to 1, a 28-Kbyte area of H'1000 to H'7FFF will be erased.
3	EB3	0	R/W	When this bit is set to 1, a 1-Kbyte area of H'0C00 to H'0FFF will be erased.
2	EB2	0	R/W	When this bit is set to 1, a 1-Kbyte area of H'0800 to H'0BFF will be erased.
1	EB1	0	R/W	When this bit is set to 1, a 1-Kbyte area of H'0400 to H'07FF will be erased.
0	EB0	0	R/W	When this bit is set to 1, a 1-Kbyte area of H'0000 to H'03FF will be erased.

Section 7 RAM (H8/38602R Group Hardware Manual Rev.3.00 Page 117 of 516)

H8/38602R Group specification

Product Classification		RAM Size	RAM Address
Flash memory version	H8/38602RF	1 Kbyte	H'FB80 to H'FF7F
Masked ROM version	H8/38602R	1 Kbyte	H'FB80 to H'FF7F
	H8/38600R	512 bytes	H'FD80 to H'FF7F

H8/38606 Group specification

Product Classification		RAM Size	RAM Address
Flash memory version	H8/38606F	2 Kbyte	H'F780 to H'FF7F

Section 21 Electrical Characteristics

21.2.2 DC Characteristics

Active mode supply current (H8/38602R Group Hardware Manual Rev.3.00 Page 395 of 516)

H8/38602R Group specification

Item	Symbol	Applicable Pins	Test Condition	Values			Unit	Notes
				Min.	Typ.	Max.		
Active mode supply current	I _{OPe1}	V _{CC}	Active (high-speed) mode, V _{CC} =3V, f _{osc} =4.2MHz	-	2.6	4.0	mA	*1 *2 4-MHz version

H8/38606 Group specification

Item	Symbol	Applicable Pins	Test Condition	Values			Unit	Notes
				Min.	Typ.	Max.		
Active mode supply current	I _{OPe1}	V _{CC}	Active (high-speed) mode, V _{CC} =3V, f _{osc} =4.2MHz	-	2.8	4.0	mA	*1 *2 4-MHz version

Appendix

C. Product Part No. Lineup (H8/38602R Group Hardware Manual Rev.3.00 Page 491 of 516)

H8/38602R Group specification

Product Classification		Product Part No.		Model Marking	Package (Package Code)
H8/38602R Group	Flash memory version	(10MHz)	HD64F38602RFT10	38602R10	32-pin QFN
		(4MHz)	HD64F38602RFT4	38602R4	(TNP-32)
	Masked ROM version	(10MHz)	HD64F38602RFH10	F38602RFH10	32-pin LQFP (32P6U-A)
		(4MHz)	HD64F38602RFH4	F38602RFH4	(32P6U-A)
H8/38600R	Masked ROM version		HD64338602RFT	38602R(***)	32-pin QFN (TNP-32)
			HD64338602RFH	38602R(***)	32-pin LQFP (32P6U-A)
	Masked ROM version		HD64338600RFT	38600R(***)	32-pin QFN (TNP-32)
			HD64338600RFH	38600R(***)	32-pin LQFP (32P6U-A)

H8/38606 Group specification

Product Classification		Product Part No.		Model Marking	Package (Package Code)
H8/38606 Group	Flash memory version	(10MHz)	HD64F38606FT10	F3860610	32-pin QFN
		(4MHz)	HD64F38606FT4	F386064	(TNP-32)